

## Vishay Semiconductors

# Silicon NPN Phototransistor, RoHS Compliant

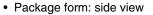


### **DESCRIPTION**

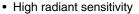
TEST2600 is a silicon NPN phototransistor with high radiant sensitivity in black, miniature, side view plastic package with daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

### **FEATURES**

• Package type: leaded



• Dimensions (L x W x H in mm): 3.6 x 2.2 x 3.4



Daylight blocking filter matches with 940 nm emitters



Fast response times

- Angle of half sensitivity:  $\varphi_1 = \pm 30^\circ$ , horizontal
- Package matches with IR emitter series TSSS2600
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

#### **APPLICATIONS**

- · Optical switches
- · Counters and sorters
- · Interrupters
- · Tape and card readers
- Encoders
- · Position sensors

PRODUCT SUMMARY			
COMPONENT	I <sub>ca</sub> (mA)	φ <b>(deg)</b>	λ <sub>0.5</sub> (nm)
TEST2600	2.5	± 30	850 to 980

### Note

Test condition see table "Basic Characteristics"

ORDERING INFORMAT				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
TEST2600	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	Side view	

#### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Collector emitter voltage		V <sub>CEO</sub>	70	V
Emitter collector voltage		V <sub>ECO</sub>	5	V
Collector current		Ic	50	mA
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA
Total power dissipation	T <sub>amb</sub> ≤ 55 °C	P <sub>V</sub>	100	mW
Junction temperature		Tj	100	°C
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C
Soldering temperature	$t \le 3$ s, 2 mm frpm case	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	R <sub>thJA</sub>	450	K/W

#### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified

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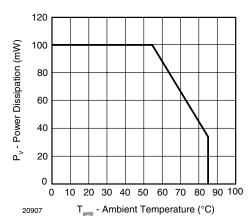


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter breakdown voltage	I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	70			V
Collector emitter dark current	V <sub>CE</sub> = 20 V, E = 0	I <sub>CEO</sub>		1	100	nA
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz, E = 0	C <sub>CEO</sub>		6		pF
Collector light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$ $V_{CE} = 5 \text{ V}$	I <sub>ca</sub>	1	2.5		mA
Angle of half sensitivity	horizontal	Ψ1		± 30		deg
	vertical	φ <sub>2</sub>		± 60		deg
Wavelength of peak sensitivity		$\lambda_{p}$		920		nm
Range of spectral bandwidth		λ <sub>0.5</sub>		850 to 980		nm
Collector emitter saturation voltage	$E_e = 1 \text{ mW/cm}^2, \ \lambda = 950 \text{ nm}, \ I_C = 0.1 \text{ mA}$	V <sub>CEsat</sub>			0.3	V
Turn-on time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>on</sub>		6		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>off</sub>		5		μs
Cut-off frequency	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	f <sub>c</sub>		110		kHz

#### Note

 $T_{amb}$  = 25 °C, unless otherwise specified

### **BASIC CHARACTERISTICS**

 $T_{amb}$  = 25 °C, unless otherwise specified

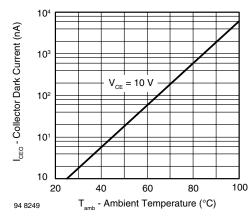


Fig. 2 - Collector Dark Current vs. Ambient Temperature

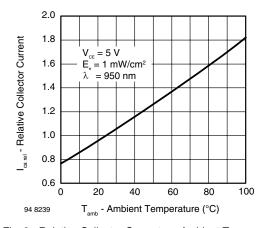


Fig. 3 - Relative Collector Current vs. Ambient Temperature



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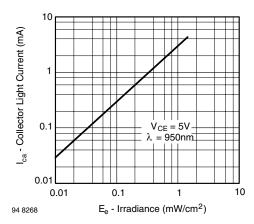


Fig. 4 - Collector Light Current vs. Irradiance

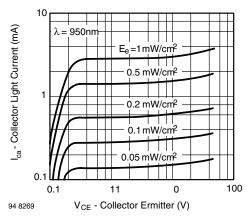


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

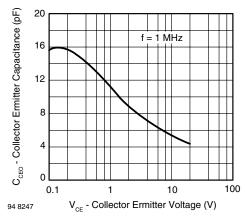


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

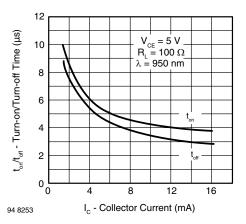


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

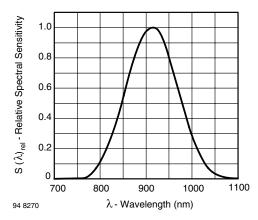


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

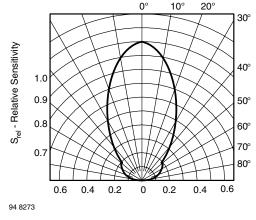


Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement

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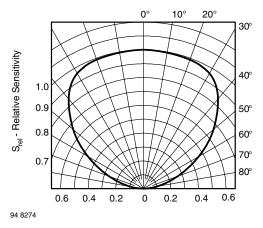
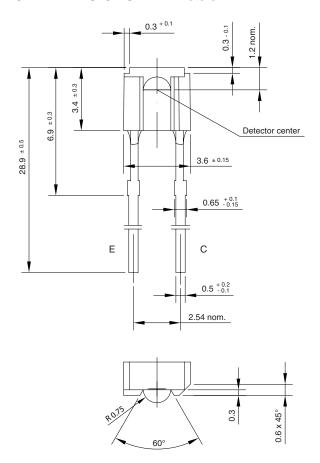
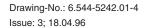


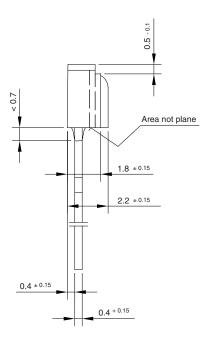
Fig. 10 - Relative Radiant Sensitivity vs. Angular Displacement

### **PACKAGE DIMENSIONS** in millimeters





95 11487







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Vishay

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